



Description

The TD101X series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic LSO package with the robust coplanar double mold structure. TD101X series provide the most stable isolation feature.

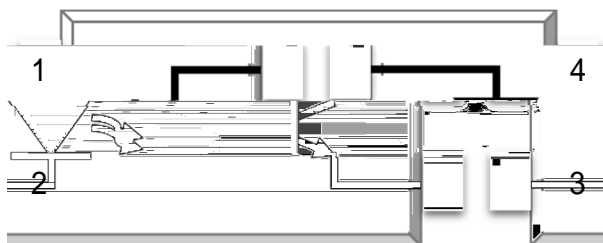
Features

- High isolation (000) * +S
- Temperature flexibility available see order information
- D, input with transistor output
- Operating temperature range . (/ , to 110 / ,
- $I_{SO} \leq 1A$, , compliance
- +SL class 1
- Regulatory Approvals
 - 2L . 2L1(33)
 -)D1 . 14503!3.(. (6)D1077!. (8
 - , 9 , : G ; !< !=#1% G ; 77<7

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

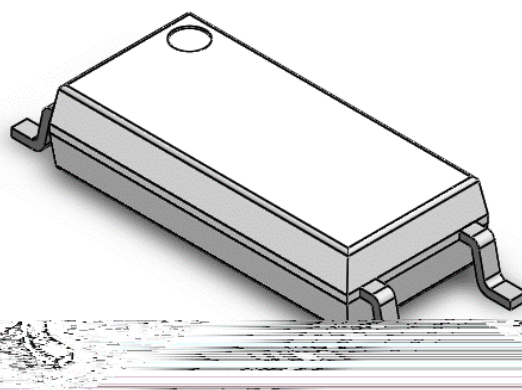
SCHEMATIC



PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE





A ' SO# " TE MA (IM " M) ATIN ! S				
A * A + 1 T 1 *	S @ + ; OL) AL 2 1	2 4 AT	4 OT 1
A 4 2 T				
Borward , urrent	A _B	50	mA	
ea" Borward , urrent	A _B	1	A	1
* e&erse) oltage) *	5)	
Anput ower Dissipation	A	100	m\$	
O 2 T 2 T				
, ollector . 1 mitter) oltage) , 1 0	70)	
1 mitter . , ollector) oltage) 1 , 0	3)	
, ollector , urrent	A ,	(0	mA	
Output ower Dissipation	o	1 (0	m\$	
, O + + O 4				
Total ower Dissipation	tot	? (0	m\$	
Asolation) oltage) iso	(0 0 0) rms	?
Operating Temperature	Topr	. ((C 1 1 0	/ ,	
Storage Temperature	Tstg	. ((C 1 ? (/ ,	
Soldering Temperature	Tsol	? 5 0	/ ,	

Note 1. 100µs pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%



ELECTRICAL CHARACTERISTICS at Ta=25°C							
Symbol	Unit	Min	Typ	Max	Test Conditions	Notes	Ref
Forward Voltage (V _F)	V	1.8	2.0	2.2	I _F = 10mA, I _R = 0		
Reverse Current (I _R)	µA	10	10	10	V _R = 5V, I _F = 0		
Input Capacitance (C _i)	pF	0	0	0	f = 1MHz, V _R = 0V		
Collector Dark Current (I _{CD})	nA	100	100	100	V _{CE} = 5V, I _B = 0		
Collector-Emitter Saturation Voltage (V _{CE(sat)})	V	0.7	0.7	0.7	I _C = 10mA, I _B = 10mA		
Emitter-Emitter Saturation Voltage (V _{EE(sat)})	V	0.3	0.3	0.3	I _E = 10mA, I _B = 10mA		
Storage Time (t _s)	µs	50	50	50	V _{CE} = 5V, I _B = 10mA, I _C = 10mA		
Turn-On Time (t _{on})	µs	100	100	100	V _{CE} = 5V, I _B = 10mA, I _C = 10mA		
Turn-Off Time (t _{off})	µs	150	150	150	V _{CE} = 5V, I _B = 10mA, I _C = 10mA		
Collector-Emitter Saturation Current (I _{CE(sat)})	mA	10	10	10	V _{CE} = 5V, I _B = 10mA		
Isolation Resistance (R _{ISO})	Ω	10 ¹¹	10 ¹¹	10 ¹¹	V _R = 50V, I _F = 0		
Bloating Capacitance (C _{BO})	pF	0	0	0	f = 1MHz, V _R = 0V		
Cutoff Frequency (f _c)	MHz	70	70	70	V _{CE} = 5V, I _B = 10mA, I _C = 10mA		
Response Time (t _r)	µs	17	17	17	V _{CE} = 5V, I _B = 10mA, I _C = 10mA		
Response Time (t _f)	µs	5	5	5	V _{CE} = 5V, I _B = 10mA, I _C = 10mA		

Note 3. Fig.12&13

Note 4. Fig.14



CHA) ACTE) ISTIC C ") - ES

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Fi..3 For /ard C&rrent 0\$. For /ard -olta.e	Fi..4 Collector Dar2 C&rrent 0\$. Am1ient Tem%erat&re

**Fi..+ Collector C&rrent
0\$. Collector3emitter -olta.e**

Fi..4 Collector C&rrent



CHARACTERISTIC CURVES

Fig. 5 Normalized Current Transfer Ratio vs. Forward Current

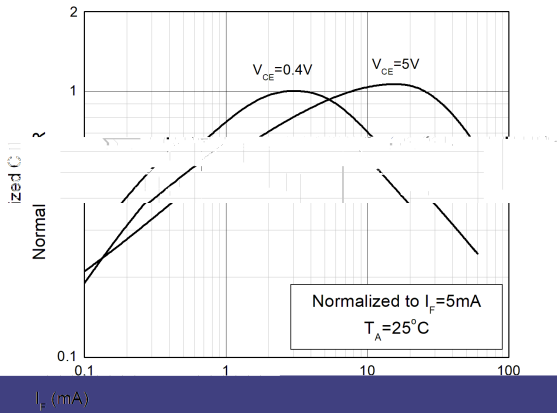


Fig. 8 Normalized Current Transfer Ratio vs. Ambient Temperature

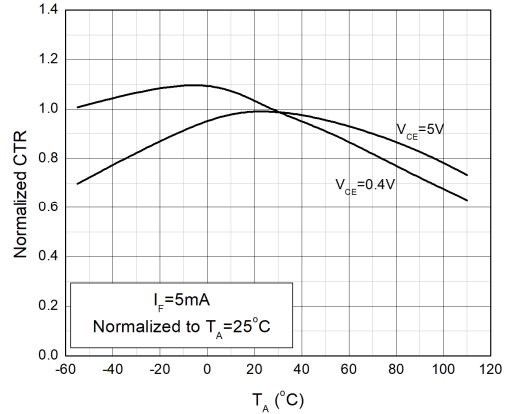


Fig. 9 Collector-Emitter Saturation Voltage vs. Ambient Temperature

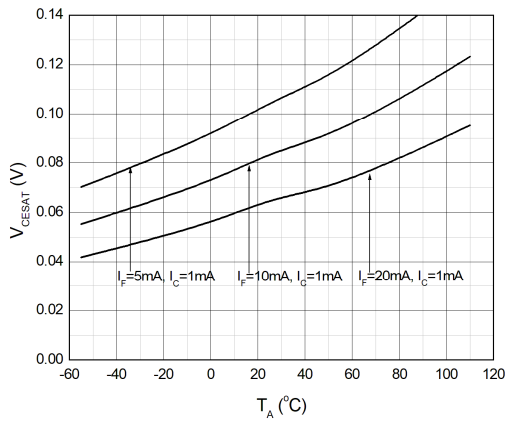


Fig. 10 Switching Time vs. Load Resistance

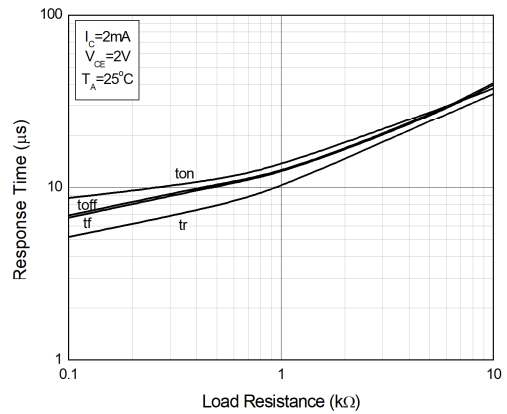
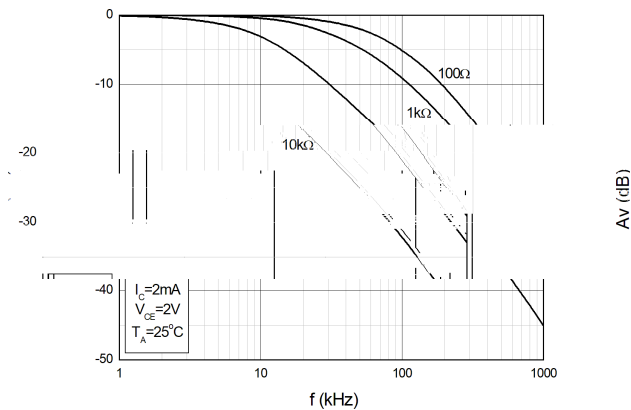


Fig. 11 Frequency Response



TEST CIRCUITS

Fig. 12 Test Circuit of Forward Time

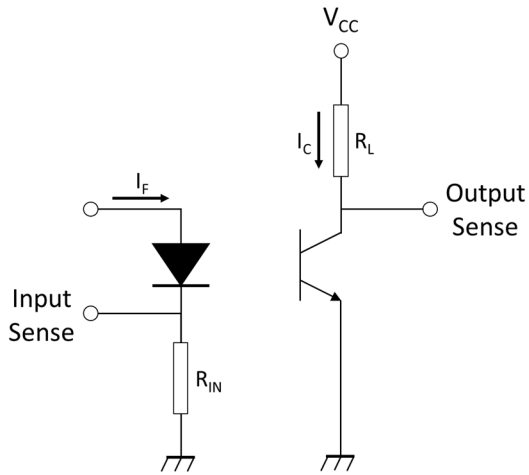


Fig. 13 Characteristic of Forward Time

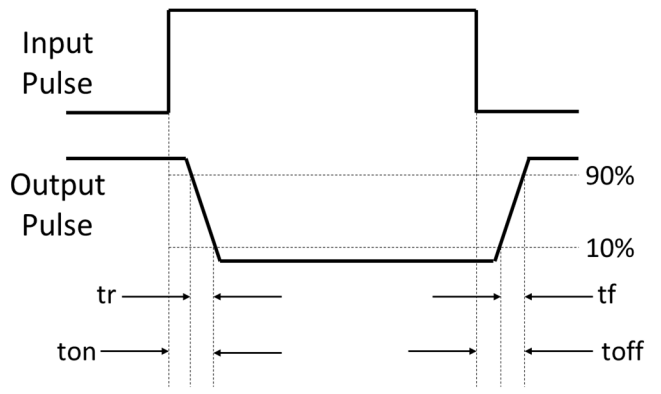
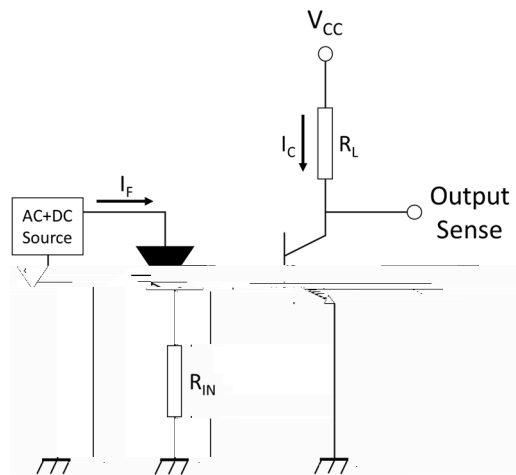
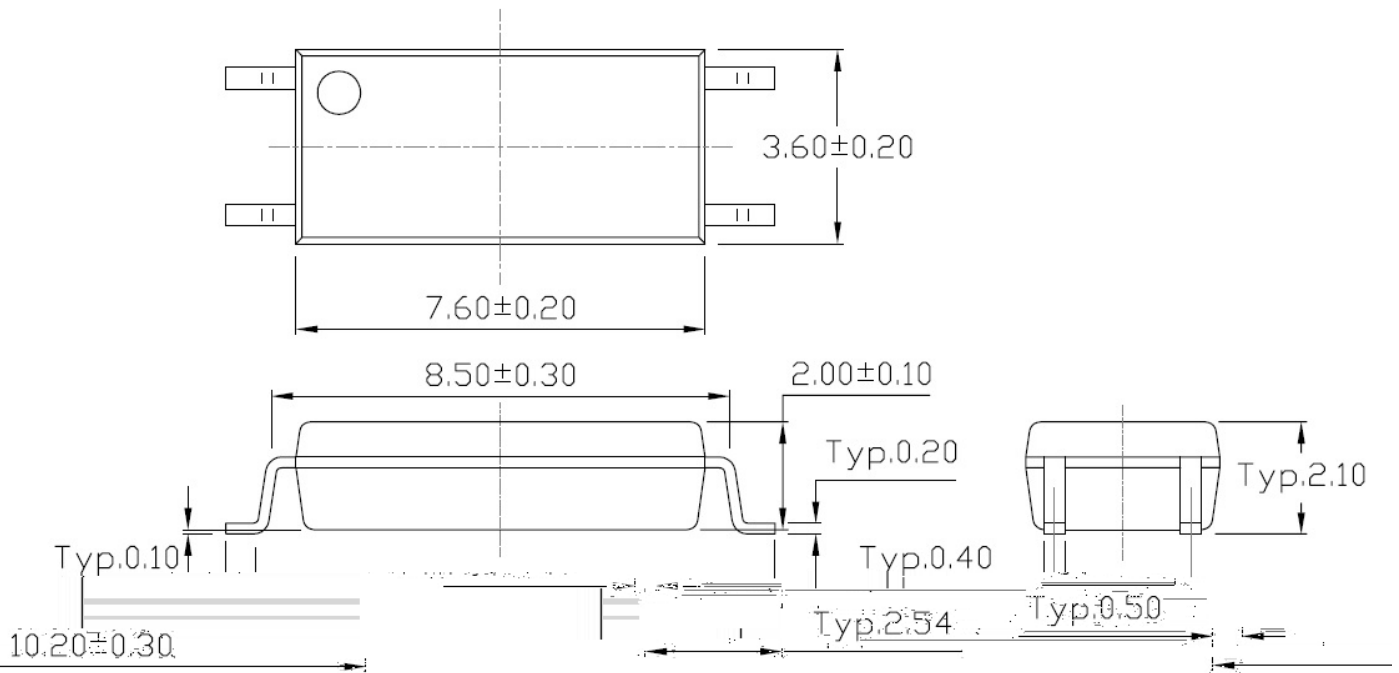


Fig. 14 Test Circuit of Reverse Time

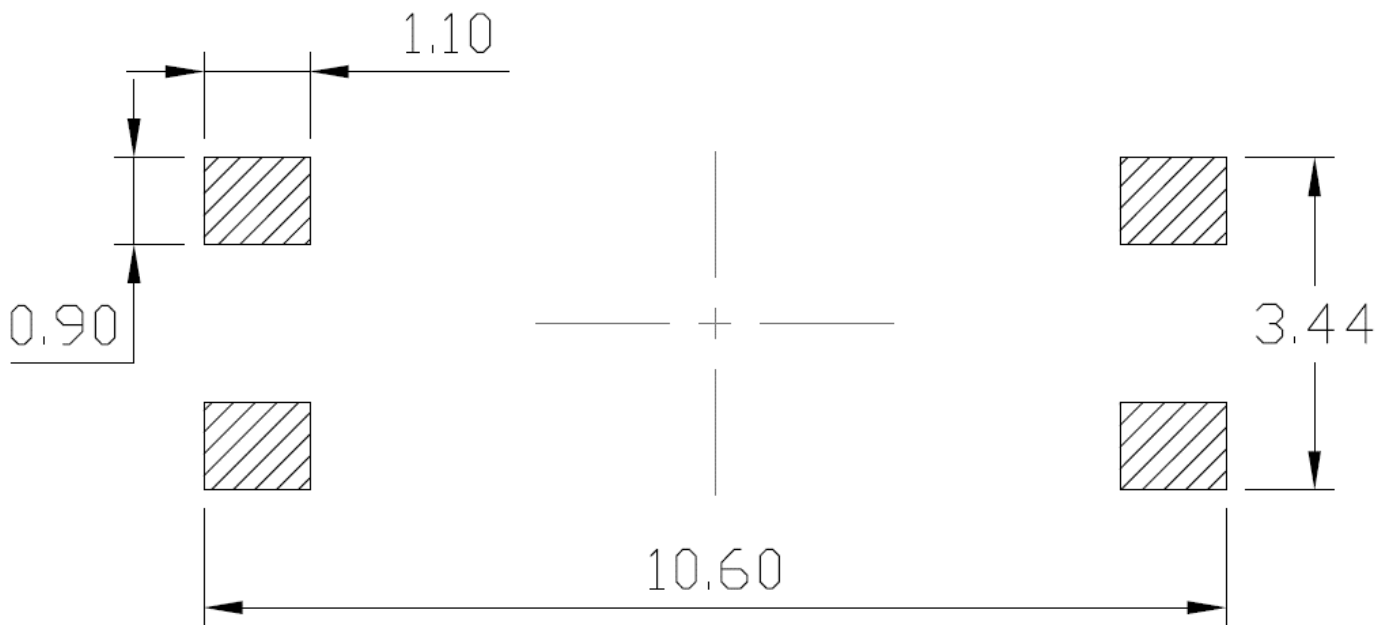




PAC A ! E DIMENSIONS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=



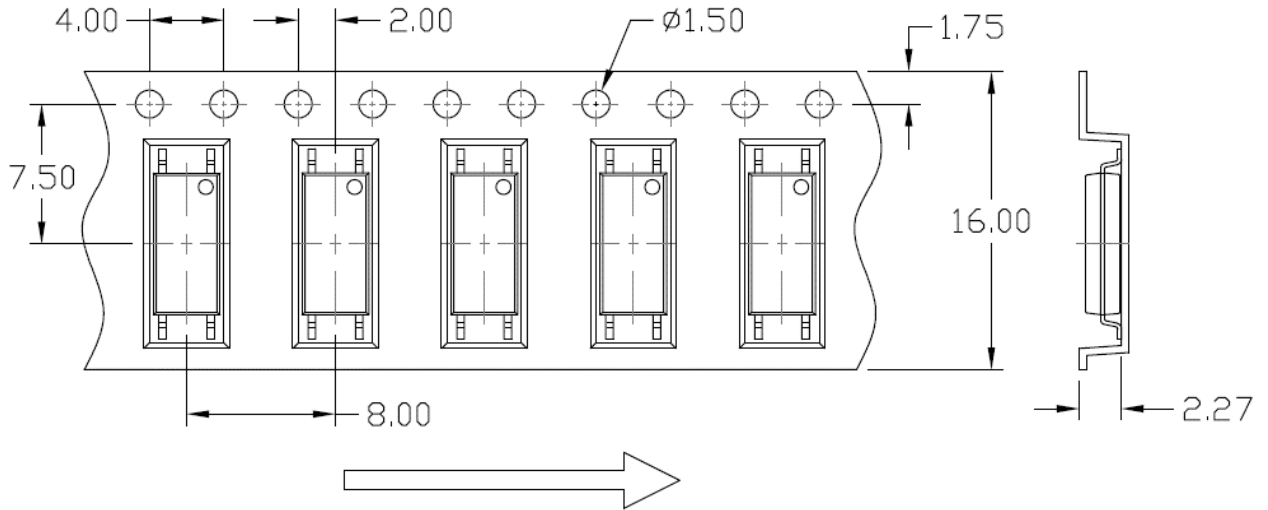
) ECOMMENDED SO#DE) MAS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=



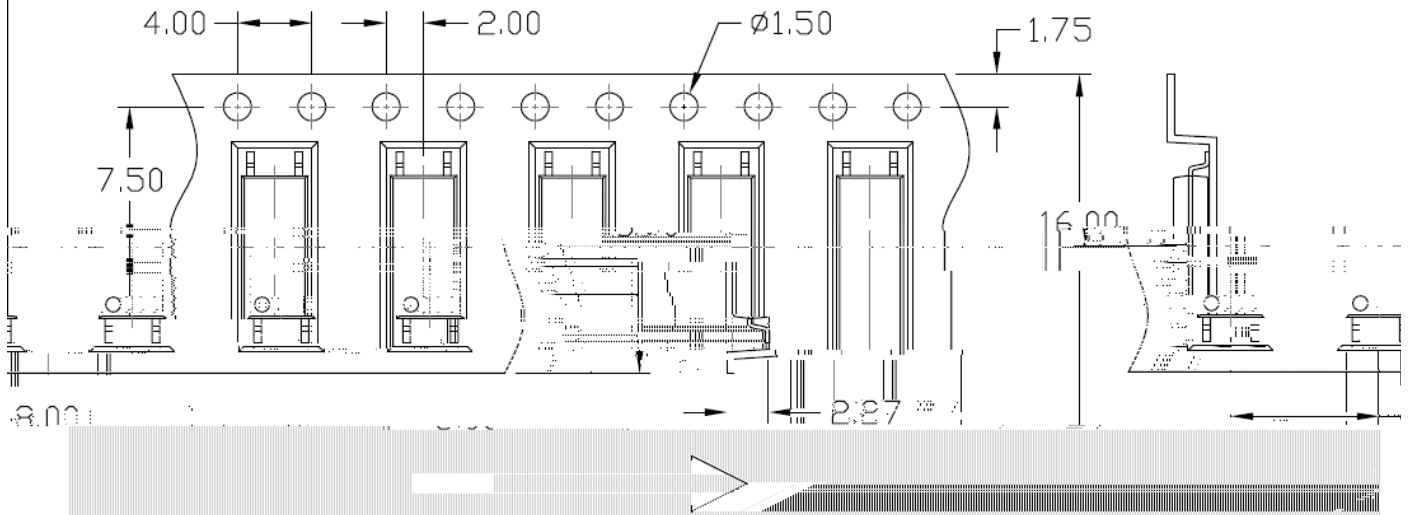


CA) IE) TAPE SPECIFICATIONS (Dimension\$ in mm & nle\$\$ other / i\$e \$ stated=

O%tion T1



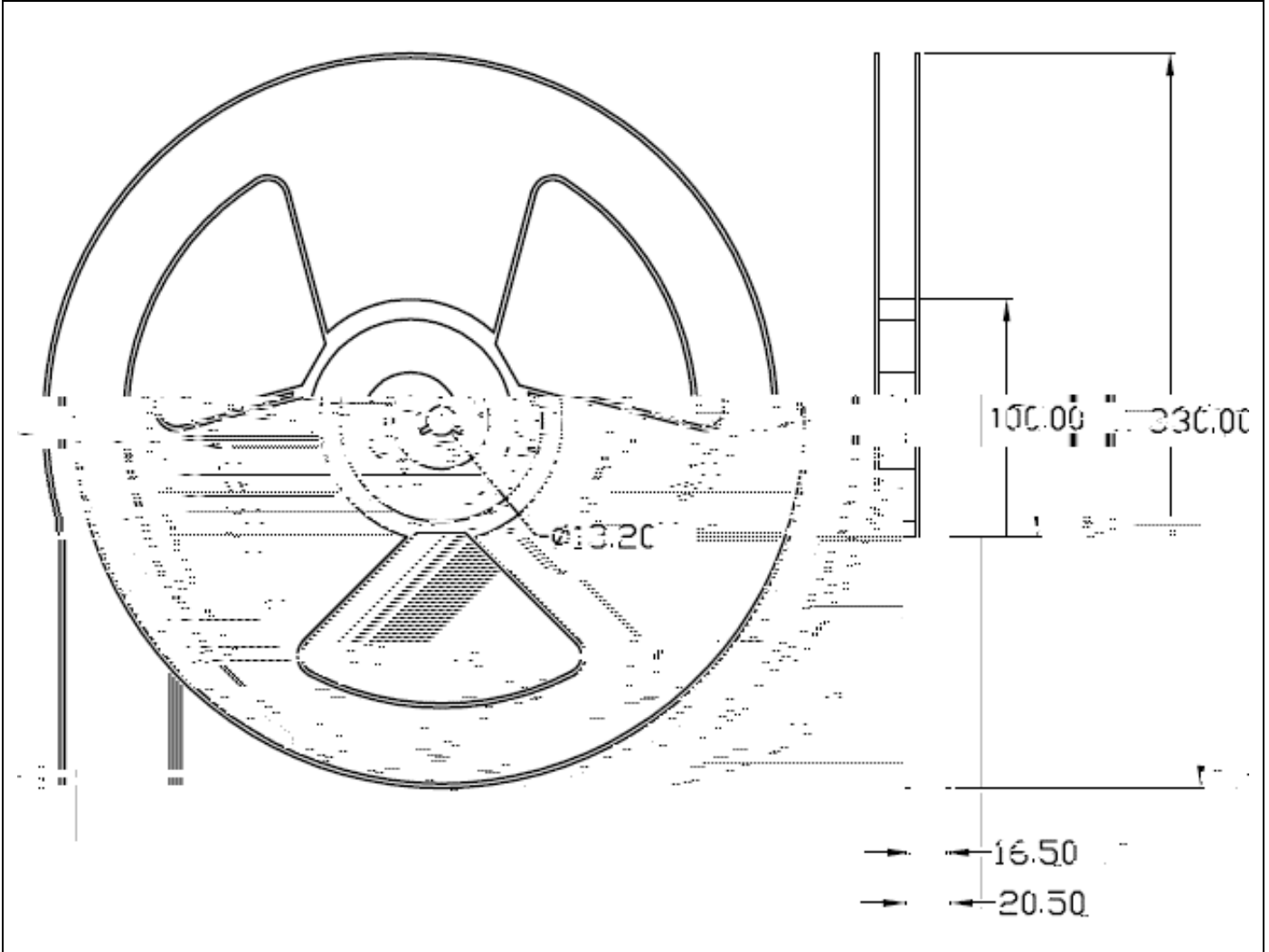
O%tion T2





) EE# SPECIFICATIONS (Dimension\$ in mm &nle\$\$ other / i\$e \$tated=

O%tion T1 > T2





TDLED SPECIFICATIONS

Inner Size

L x W x H = 36cm x 36cm x 6.9cm



O)DE)IN! AND MA) IN! INFO)MATION

MA) IN! INFO)MATION



TD @ Com%an< A11r.
1:1(@ Part N&m1er >)an2
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 101X : * an" 60J1J?J=J!J(J5J3J7J<8
 K : Tape and * eel Option 6T1JT?8
 G : Green
) :)D1 Option 6) or 4one8



福建天电光电有限公司
FUJIAN LIGHTNING OPTOELECTRONIC CO., LTD.

Part No : XXXXXXXXXXXXX Bin Code : X



Lot No : XXXXXXXXXXXX

Date Code : XXXX

Q'ty : XXXX pcs





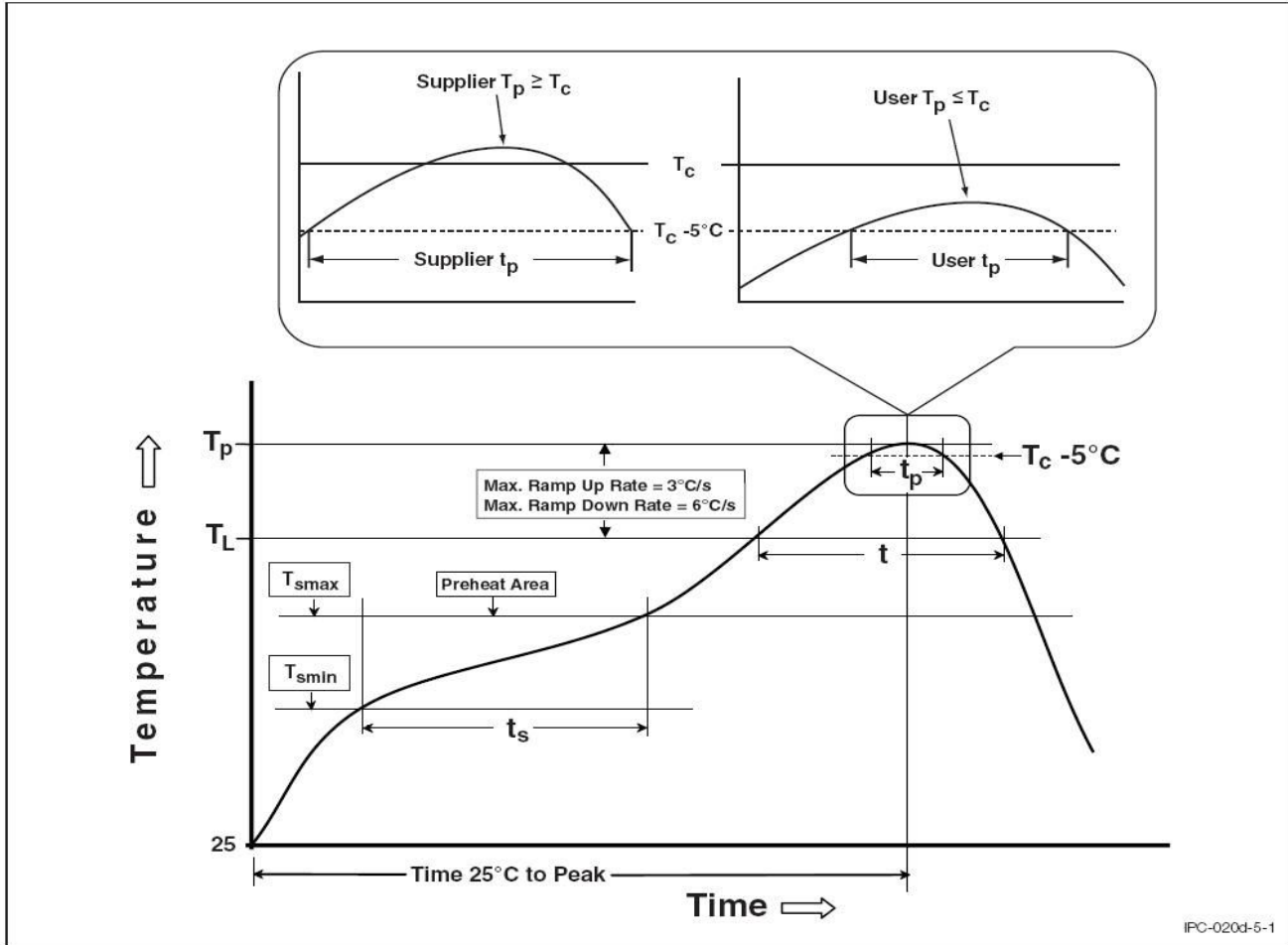
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O%tion	E&antit<	E&antit< F Inner 1o?	E&antit< F O&ter 1o?
T1	=000 2nitsJ * eel	= * eelsJanner bo-	(Anner bo-JOuter bo- D ! (" 2nits
T?	=000 2nitsJ * eel	= * eelsJanner bo-	(Anner bo-JOuter bo- D ! (" 2nits



PROFILE INFORMATION

PROFILE OF THE



IPC-020d-5-1

Profile Feature	Sn3Pb Assembly Profile	PbFree Assembly Profile
Temperature +in# T_{smin}	100	100
Temperature +a-# T_{smax}	100	100
Time t_s from T_{smin} to T_{smax}	50.1±0 seconds	50.1±0 seconds
* ramp.up * ate T_L to T_p	=/ , Jsecond ma-#	=/ , Jsecond ma-#
Liquidus Temperature T_L	170	130
Time t_L + aintained Abo&e T_L	50 : 10 seconds	50 : 10 seconds
ea" ;ody ac"age Temperature	170, 100, 100	150, 100, 100
Time t_p within (/ , of 150 / ,	±0 seconds	±0 seconds
* amp.down * ate T_p to T_L	5 / , Jsecond ma-	5 / , Jsecond ma-
Time (/ , to ea" Temperature	5 minutes ma-#	7 minutes ma-#



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